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April 1st, 2010 Renesas Electronics Corporation

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HZM-N Series

Silicon Epitaxial Planar Zener Diode for Stabilizer

REJ03G0483-0500

(Previous: ADE-208-130D)

Rev.5.00 Dec 14, 2004

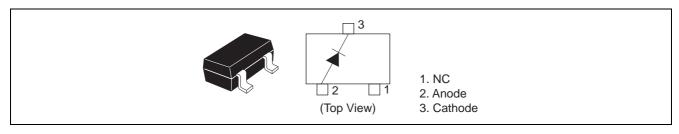
Features

- Wide spectrum from 1.9 V through 38 V of zener voltage provide flexible application.
- MPAK Package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HZM-N Series	Let to Mark Code	MPAK

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Power dissipation	Pd *1	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	−55 to +150	°C

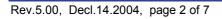
Note: 1. See Fig. 3.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

		Zener Voltage				Reverse Current Dy		Dynamic Resistance	
				Test		Test		Test	
		V _z ((V)* ¹	Condition	I _R (μ A)	Condition	r _d (Ω)	Condition	
Type	Grade	Min	Max	I _Z (mA)	Max	V _R (V)	Max	I _Z (mA)	
HZM2.0N	В	1.90	2.20	5	120	0.5	100	5	
HZM2.2N	В	2.10	2.40	5	120	0.7	100	5	
HZM2.4N	В	2.30	2.60	5	120	1.0	100	5	
HZM2.7N	В	2.50	2.90	5	120	1.0	110	5	
	B1	2.50	2.75						
	B2	2.65	2.90	1					
HZM3.0N	В	2.80	3.20	5	50	1.0	120	5	
	B1	2.80	3.05	1					
	B2	2.95	3.20	1					
HZM3.3N	В	3.10	3.50	5	20	1.0	130	5	
	B1	3.10	3.35	1					
	B2	3.25	3.50	1					
HZM3.6N	В	3.40	3.80	5	10	1.0	130	5	
	B1	3.40	3.65	1					
	B2	3.55	3.80	1					
HZM3.9N	В	3.70	4.10	5	10	1.0	130	5	
	B1	3.70	3.97	1					
	B2	3.87	4.10	1					
HZM4.3N	В	4.01	4.48	5	10	1.0	130	5	
	B1	4.01	4.21						
	B2	4.15	4.34						
	В3	4.28	4.48						
HZM4.7N	В	4.42	4.90	5	10	1.0	130	5	
	B1	4.42	4.61	1					
	B2	4.55	4.75	1					
	В3	4.69	4.90	1					
HZM5.1N	В	4.84	5.37	5	5	1.5	130	5	
	B1	4.84	5.04	1					
	B2	4.98	5.20	1					
	В3	5.14	5.37	1					
HZM5.6N	В	5.31	5.92	5	5	2.5	80	5	
	B1	5.31	5.55	1					
	B2	5.49	5.73	1					
	В3	5.67	5.92	1					

Note: 1. Tested with pulse (P_W = 40 ms)



			Zener Volt	age	age Reverse Current		Dynamic Resistance	
			n n+1	Test	1 (4)	Test	(O)	Test
Туре	Grade	V _Z ((V)* ¹ Max	Condition I _Z (mA)	I _R (μA) Max	Condition	r _d (Ω) Max	Condition
HZM6.2N	В	5.86	6.53	5	2	V _R (V) 3.0	50	I z (mA)
TIZIVIO.ZIV	B1	5.86	6.12	J		3.0	30	
	B2	6.06	6.33					
	B3	6.26	6.53					
HZM6.8N	В	6.47	7.14	5	2	3.5	30	5
I IZIVIO.OIN	B1	6.47	6.73	3		3.5	30	3
	B2	6.65	6.93					
	B3	6.86	7.14					
HZM7.5N	В	7.06	7.14	5	2	4.0	30	5
HZIVI7.SIN	B1			5		4.0	30	5
		7.06	7.36					
	B2	7.28	7.60					
117040 001	B3	7.52	7.84		0	5.0	20	
HZM8.2N	B	7.76	8.64	5	2	5.0	30	5
	B1	7.76	8.10					
	B2	8.02	8.36					
117040 401	B3	8.28	8.64	_		0.0		
HZM9.1N	В	8.56	9.55	5	2	6.0	30	5
	B1	8.56	8.93					
	B2	8.85	9.23					
	B3	9.15	9.55	_				_
HZM10N	В	9.45	10.55	5	2	7.0	30	5
	B1	9.45	9.87					
	B2	9.77	10.21					
	B3	10.11	10.55					
HZM11N	В	10.44	11.56	5	2	8.0	30	5
	B1	10.44	10.88					
	B2	10.76	11.22					
	B3	11.10	11.56					
HZM12N	В	11.42	12.60	5	2	9.0	35	5
	B1	11.42	11.90					
	B2	11.74	12.24					
	B3	12.08	12.60					
HZM13N	В	12.47	13.96	5	2	10.0	35	5
	B1	12.47	13.03					
	B2	12.91	13.49					
	B3	13.37	13.96					
5M15N	В	13.84	15.52	5	2	11.0	40	5
	B1	13.84	14.46					
	B2	14.34	14.98					
	В3	14.85	15.52					
HZM16N	В	15.37	17.09	5	2	12.0	40	5
	B1	15.37	16.01					
	B2	15.85	16.51					
	В3	16.35	17.09					
HZM18N	В	16.94	19.03	5	2	13.0	45	5
	B1	16.94	17.70					
	B2	17.56	18.35					
	В3	18.21	19.03					

Note: 1. Tested with pulse ($P_W = 40 \text{ ms}$)

		Zener Voltage		Revers	Reverse Current		Dynamic Resistance	
		V _z (V)* ¹	Test Condition	I _R (μ A)	Test Condition	r _d (Ω)	Test Condition
Type	Grade	Min	Max	I _Z (mA)	Max	V _R (V)	Max	I _Z (mA)
HZM20N	В	18.86	21.08	5	2	15.0	50	5
	B1	18.86	19.70					
	B2	19.52	20.39					
	В3	20.21	21.08					
HZM22N	В	20.88	23.17	5	2	17.0	55	5
	B1	20.88	21.77					
	B2	21.54	22.47					
	В3	22.23	23.17					
HZM24N	В	22.93	25.57	5	2	19.0	60	5
	B1	22.93	23.96					
	B2	23.72	24.78					
	В3	24.54	25.57					
HZM27N	В	25.10	28.90	2	2	21.0	70	2
HZM30N	В	28.00	32.00	2	2	23.0	80	2
HZM33N	В	31.00	35.00	2	2	25.0	80	2
HZM36N	В	34.00	38.00	2	2	27.0	90	2

Note: 1. Tested with pulse ($P_W = 40 \text{ ms}$)

Mark Code

Type	Grade	Mark No.
HZM2.0N	В	20-
HZM2.2N	В	22-
HZM2.4N	В	24-
HZM2.7N	B1	271
	B2	272
HZM3.0N	B1	3 0 1
	B2	302
HZM3.3N	B1	3 3 1
	B2	3 3 2
HZM3.6N	B1	3 6 1
	B2	362
HZM3.9N	B1	3 9 1
	B2	392
HZM4.3N	B1	4 3 1
	B2	432
	В3	4 3 3
HZM4.7N	B1	471
	B2	472
	В3	473
HZM5.1N	B1	5 1 1
	B2	512
	В3	5 1 3
HZM5.6N	B1	561
	B2	562
	В3	563

Туре	Grade	Mark No.
HZM6.2N	B1	621
	B2	622
	В3	623
HZM6.8N	B1	681
	B2	682
	В3	683
HZM7.5N	B1	751
	B2	752
	В3	753
HZM8.2N	B1	821
	B2	822
	B3	823
HZM9.1N	B1	911
	B2	912
	В3	913
HZM10N	B1	<u>1</u> 0 1
	B2	<u>1</u> 02
	B3	<u>1</u> 03
HZM11N	B1	<u>1</u> 1 1
	B2	<u>1</u> 1 2
	В3	<u>1</u> 1 3
HZM12N	B1	<u>1</u> 21
	B2	<u>1</u> 22
	В3	<u>1</u> 23

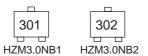
Туре	Grade	Mark No.
HZM13N	B1	<u>1</u> 3 1
	B2	<u>1</u> 32
	В3	<u>1</u> 33
HZM15N	B1	<u>1</u> 51
	B2	<u>1</u> 52
	В3	<u>1</u> 53
HZM16N	B1	<u>1</u> 61
	B2	<u>1</u> 62
	В3	<u>1</u> 63
HZM18N	B1	<u>1</u> 81
	B2	<u>1</u> 82
	В3	<u>1</u> 83
HZM20N	B1	<u>2</u> 0 1
	B2	<u>2</u> 0 2
	В3	<u>2</u> 0 3
HZM22N	B1	<u>2</u> 2 1
	B2	<u>2</u> 2 2
	В3	<u>2</u> 2 3
HZM24N	B1	<u>2</u> 4 1
	B2	<u>2</u> 4 2
	В3	<u>2</u> 4 3
HZM27N	В	<u>2</u> 7-
HZM30N	В	<u>3</u> 0-
HZM33N	В	<u>3</u> 3 –
HZM36N	В	<u>3</u> 6 –

Example of Marking

1. One grade type (grade type B)



2. Two grade type (B1, B2)



3. Three grade type (B1, B2, B3)



Notes: 1. The grade B type includes from B1 min. to B3 (or B2) max.

- 2. B grade is standard and has better delivery, These are marked one of B1, B2, B3.
- 3. Ordering P/N HZM-N series are delivered taped (TL/TR). Choose one taping code and adhere to parts No.

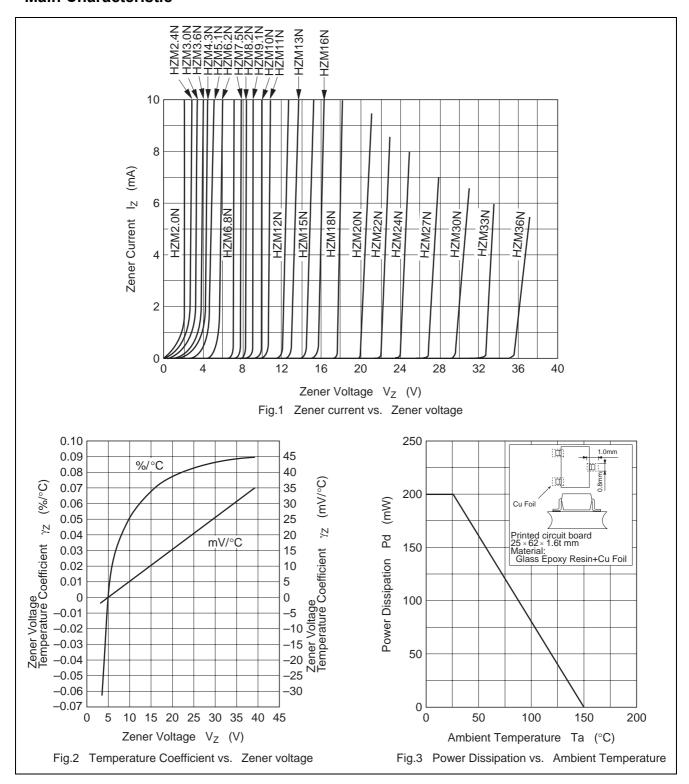
Example: HZM2.0NBTL (or TR), HZM2.2NBTL (or TR), HZM36NBTL (or TR).

(Grade B type)

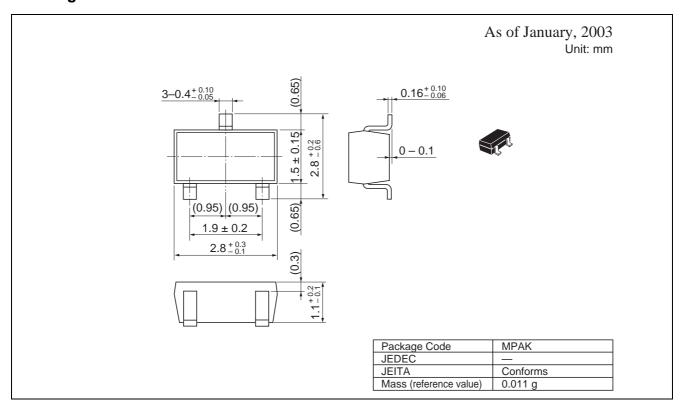
HZM2.7NB1TL (or TR), HZM2.7NB2TL (or TR), HZM24NB3TL (or TR).

(Grade B1, B2, B3 type)

Main Characteristic



Package Dimensions



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